

GNSS LOW NOISE AMPLIFIER

■ GENERAL DESCRIPTION

The NJG1155UX2 is a low noise amplifier GaAs MMIC designed for GNSS (Global Navigation Satellite Systems). The NJG1155UX2 is featured low noise figure, and operates from 1.5V to 3.3V single voltage. The NJG1155UX2 has stand-by mode to save the supply current, has the on-chip ESD protection devices.

The NJG1155UX2 achieves ultra small mounting area by only two external components and ultra small package that is lead-free and halogen-free 6-pin EPFFP6-X2 package.

■ PACKAGE OUTLINE



■ APPLICATIONS

GNSS applications, like GPS, Galileo, GLONASS and COMPASS.

■ FEATURES

Operating frequencies
 Low supply voltage
 1550 to 1615MHz
 2.8 / 1.8V typ.

• Low current consumption 3.5 / 3.1 mA typ. @V_{DD}=2.8 / 1.8V, V_{CTL}=1.8V

19.0 / 18.5dB typ. $@V_{DD}=2.8 / 1.8V, V_{CTL}=1.8V$ 0.75dB typ. $@V_{DD}=2.8 / 1.8V, V_{CTL}=1.8V$

EPFFP6-X2 (Package size: 1.1mm x 0.7mm x 0.37mm typ.)

2pcs.

High gain

Low noise figure

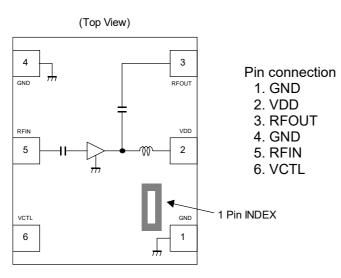
Ultra small package

Low external component count

RoHS compliant and Halogen Free

MSL1

■ PIN CONFIGURATION



■ TRUTH TABLE

V _{CTL}	LNA mode
Н	Active mode
L	Stand-by mode

"H"=V_{CTL(H)}, "L"=V_{CTL(L)}

Note: Specifications and description listed in this datasheet are subject to change without notice.

■ ABSOLUTE MAXIMUM RATINGS

General conditions: T_a =+25°C, Z_s = Z_l =50 Ω

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V_{DD}		5.0	V
Control voltage	V_{CTL}		5.0	V
Input power	P _{IN}	V _{DD} =2.8V	+15	dBm
Power dissipation	P_D	4-layer FR4 PCB without through-hole (101.5mm x 114.5mm), T _j =150°C	430	mW
Operating temperature	T_{opr}		-40 to +85	°C
Storage temperature	T_{stg}		-55 to +150	°C

■ ELECTRICAL CHARACTERISTICS 1 (DC)

General conditions: T_a =+25°C, Z_s = Z_l =50 Ω

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD}		1.5	ı	3.3	V
Control Voltage (High)	V _{CTL(H)}		1.2	1.8	3.3	V
Control Voltage (Low)	V _{CTL(L)}		0	0	0.3	V
Supply Current1 (Active mode)	I _{DD1}	V _{DD} =2.8V, V _{CTL} =1.8V	1	3.5	6.0	mA
Supply Current2 (Active mode)	I _{DD2}	V _{DD} =1.8V, V _{CTL} =1.8V	1	3.1	5.5	mA
Supply Current3 (Stand-by mode)	I _{DD3}	V _{DD} =2.8V, V _{CTL} =0V	-	0.1	3.0	μA
Supply Current4 (Stand-by mode)	I _{DD4}	V _{DD} =1.8V, V _{CTL} =0V	-	0.1	3.0	μA
Control Current	I _{CTL}	V _{CTL} =1.8V	-	5.0	12.0	μA

■ ELECTRICAL CHARACTERISTICS 2 (RF, V_{DD}=2.8V)

General conditions: V_{DD} =2.8V, V_{CTL} =1.8V, f_{RF} =1550 to1615MHz, T_a =+25°C, Z_s = Z_l =50 Ω , with application circuit **PARAMETER SYMBOL CONDITIONS** MIN **TYP** MAX UNITS Exclude PCB and connector Small Signal Gain1 Gain1 16.5 19.0 21.0 dB losses (0.18dB) Exclude PCB and connector NF1 0.75 1.0 Noise Figure1 dΒ losses (0.08dB) Isolation1 ISL1 25.0 35.0 dB Input Power at 1dB Gain P-_{1dB} (IN)1 -17.0 -12.5 dBm Compression Point1 Input 3rd Order Intercept $f1=f_{RF}$, f2=f1+/-1MHz, IIP3_1 -5.0 -1.5 dBm Point1 Pin=-30dBm f₁=1712.7MHz, Pin=-20dBm, Out of Band Input 3rd f₂=1850MHz, Pin=-20dBm, IIP3 OB1 -4.0 0.0 dBm Order Intercept Point1 f_{meas} =1575.4MHz 10.0 **RFIN Port Return Loss1** RLi1 6.0 dΒ **RFOUT Port Return Loss1** RLo1 8.0 12.0 dB

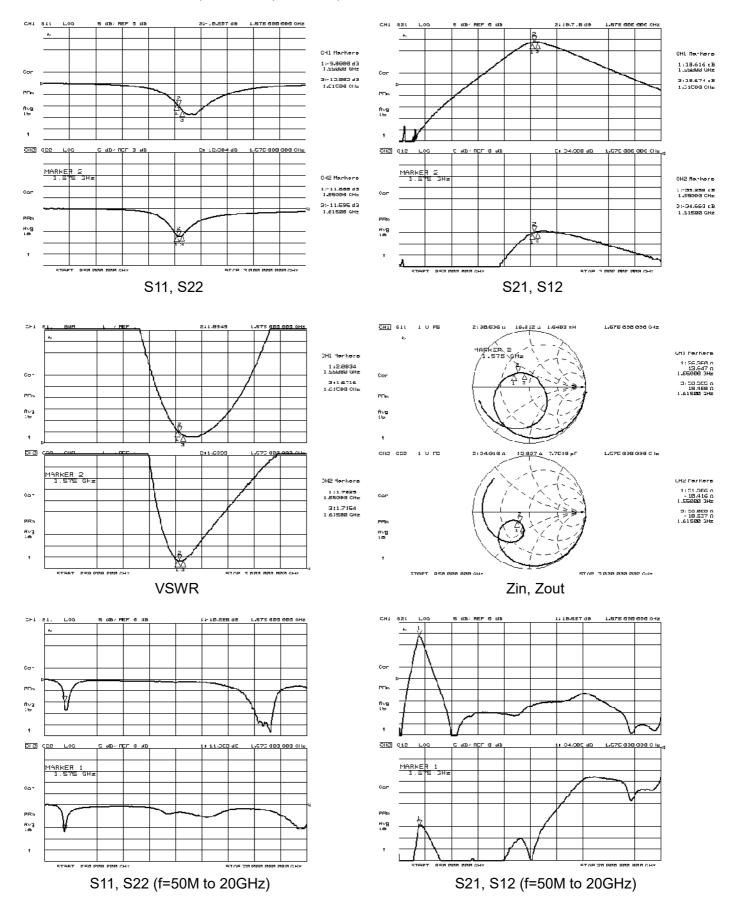
■ ELECTRICAL CHARACTERISTICS 3 (RF, V_{DD}=1.8V)

General conditions: V_{DD} =1.8V, V_{CTL} =1.8V, f_{RF} =1550 to1615MHz, T_a =+25°C, Z_s = Z_l =50 Ω , with application circuit						
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small Signal Gain2	Gain2	Exclude PCB and connector losses (0.18dB)	15.0	18.5	21.0	dB
Noise Figure2	NF2	Exclude PCB and connector losses (0.08dB)	-	0.75	1.1	dB
Isolation2	ISL2		25.0	35.0	ı	dB
Input Power at 1dB Gain Compression Point2	P- _{1dB} (IN)2		-20.0	-16.0	1	dBm
Input 3rd Order Intercept Point2	IIP3_2	f1=f _{RF} , f2=f1+/-1MHz, Pin=-30dBm	-10.0	-5.0	1	dBm
Out of Band Input 3rd Order Intercept Point2	IIP3_OB2	f_1 =1712.7MHz, Pin=-20dBm, f_2 =1850MHz, Pin=-20dBm, f_{meas} =1575.4MHz	-7.0	-3.0	-	dBm
RF IN Port Return Loss2	RLi2		6.0	10.0	-	dB
RF OUT Port Return Loss2	RLo2		7.0	12.0	-	dB

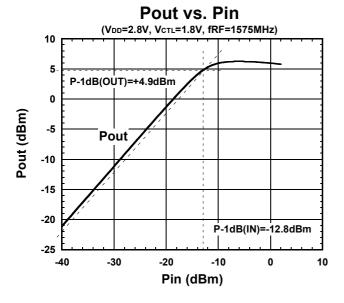
■ TERMINAL INFORMATION

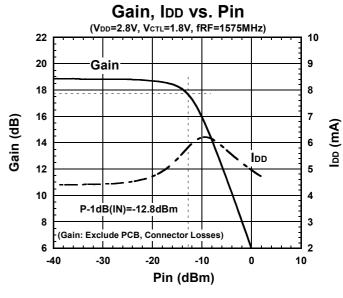
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. This terminal should be connected to the ground plane as close as possible for excellent RF performance.
2	VDD	Supply voltage terminal. Please connect bypass capacitor C1 with ground as close as possible.
3	RFOUT	RF output terminal. This terminal requires no DC blocking capacitor since this IC has internal output matching circuit including DC blocking capacitor.
4	GND	Ground terminal. This terminal should be connected to the ground plane as close as possible for excellent RF performance.
5	RFIN	RF input terminal. This terminal requires only a matching inductor L1, and does not require DC blocking capacitor.
6	VCTL	Control voltage terminal.

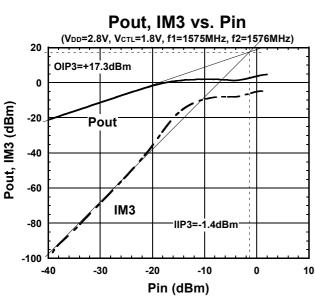
Conditions: V_{DD} =2.8V, V_{CTL} =1.8V, Ta=25°C, Z_s = Z_l =50 Ω

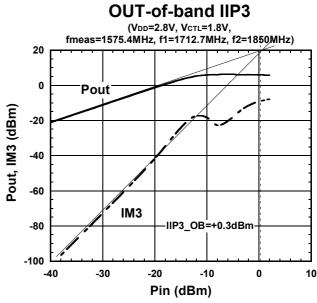


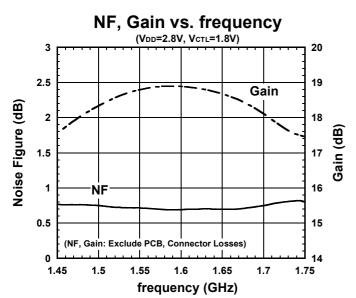
Conditions: V_{DD} =2.8V, V_{CTL} =1.8V, Ta=25°C, Z_s = Z_l =50 Ω



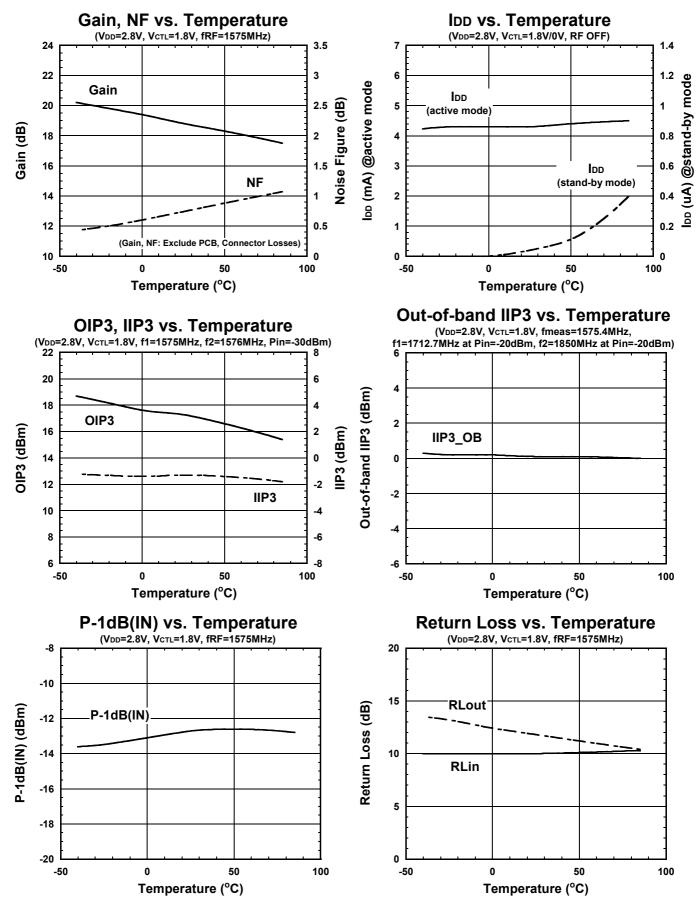




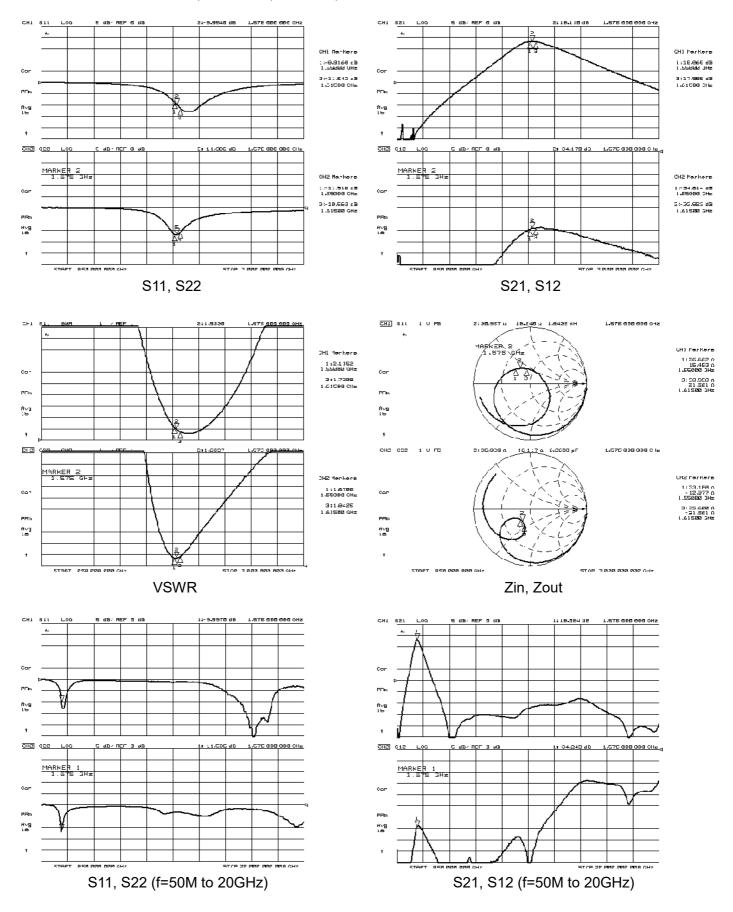




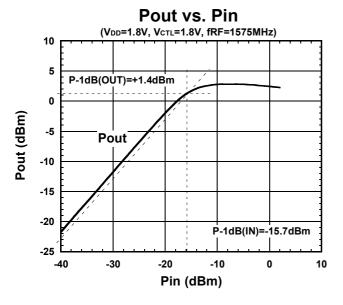
Conditions: V_{DD} =2.8V, V_{CTL} =1.8V, f_{RF} =1575MHz, Z_s = Z_l =50 Ω

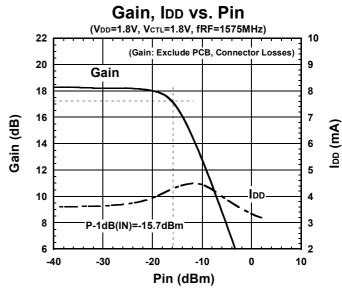


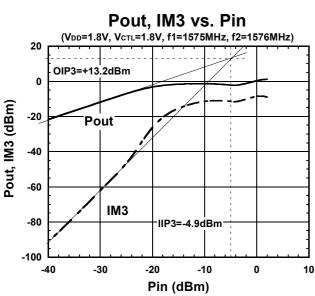
Conditions: V_{DD} =1.8V, V_{CTL} =1.8V, Ta=25°C, Z_s = Z_l =50 Ω

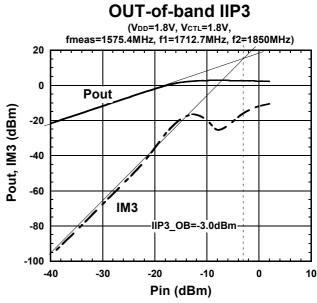


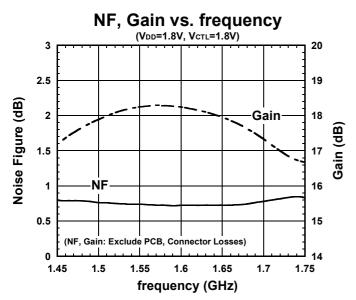
Conditions: V_{DD} =1.8V, V_{CTL} =1.8V, Ta=25°C, Z_s = Z_l =50 Ω



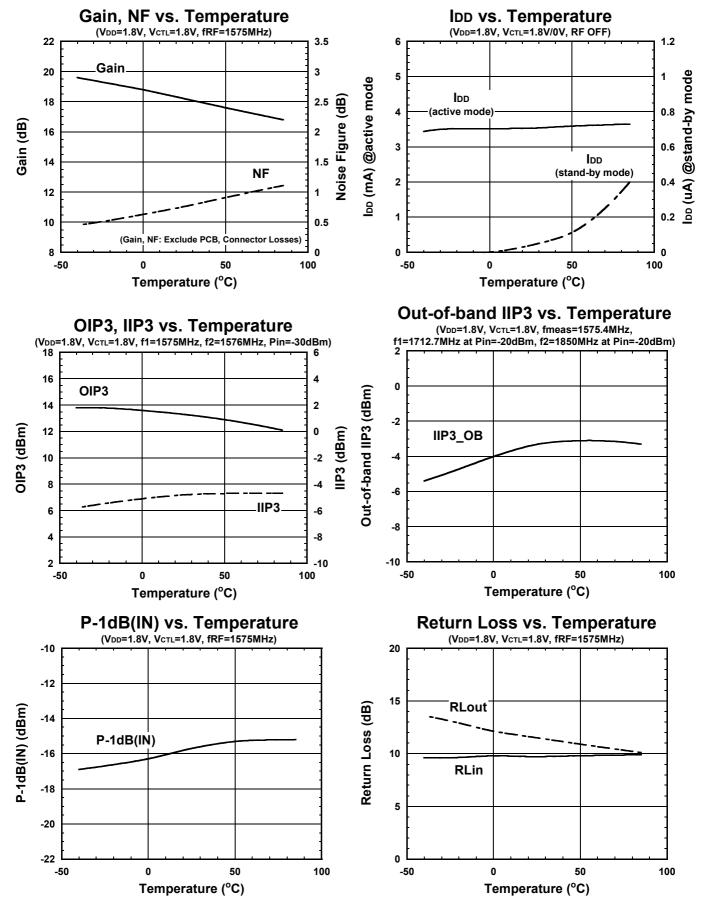






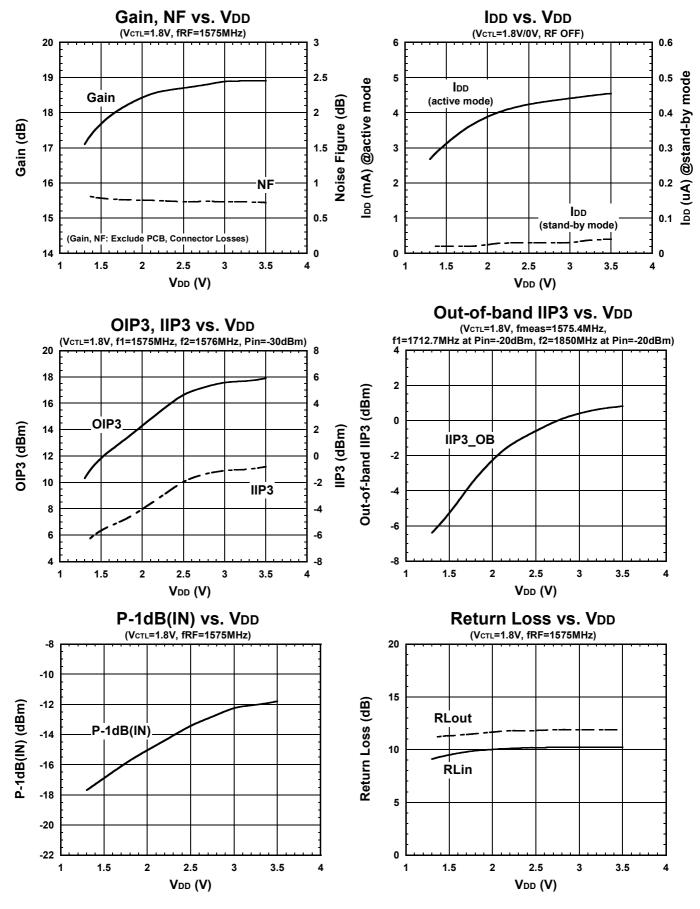


Conditions: V_{DD} =1.8V, V_{CTL} =1.8V, f_{RF} =1575MHz, Z_s = Z_l =50 Ω



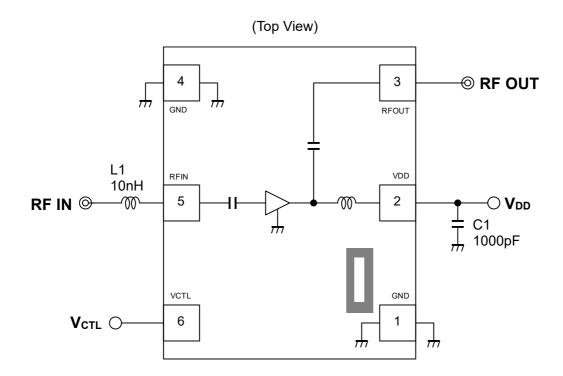
Nisshinbo Micro Devices Inc.

Conditions: V_{CTL} =1.8V, f_{RF} =1575MHz, Ta=25°C, Z_s = Z_l =50 Ω



Nisshinbo Micro Devices Inc.

■ APPLICATION CIRCUIT

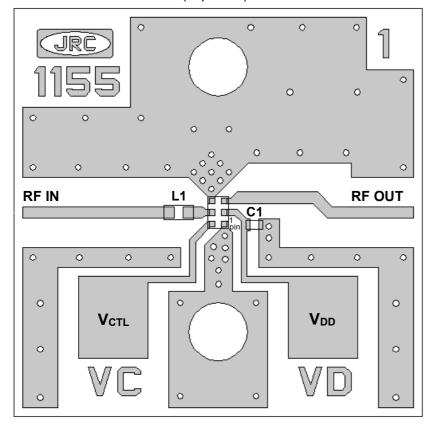


Parts list

Parts ID	Manufacture		
L1	LQG15HS Series (MURATA)		
C1	GRM03 Series (MURATA)		

■ EVALUATION BOARD

(Top View)



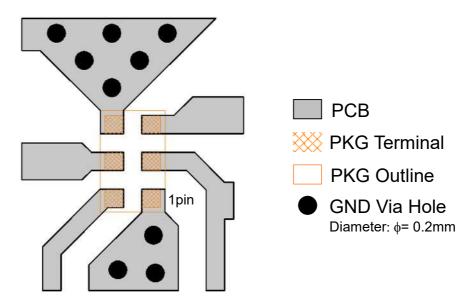
PCB Information

Substrate: FR-4 Thickness: 0.2mm Microstrip line width:

0.4mm ($Z_0 = 50\Omega$)

Size: 14.0mm x 14.0mm

<PCB LAYOUT GUIDELINE>



PRECAUTIONS

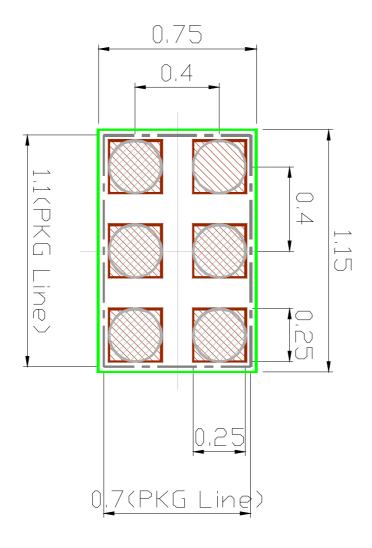
- All external parts should be placed as close as possible to the IC.
- For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the IC.

■ RECOMMENDED FOOTPRINT PATTERN (EPFFP6-X2 PACKAGE)

PKG: 1.1mm x 0.7mm Pin pitch: 0.4mm : Land

: Mask (Open area) *Metal mask thickness : $100\mu m$

: Resist (Ópen areá)



APPLICATION NOTE FOR ULTRA LOW NOISE FIGURE (Using LQW15A Series high-Q inductor)

This application note shows an example in order to achieve ultra low noise figure (NF). LQW15A (MURATA) Series inductor is used for this application.

The example of electrical characteristics are shown as follows:

■ ELECTRICAL CHARACTERISTICS (DC)

	General conditions: T_a =+25°C, Z_s = Z_l =			
PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Supply Voltage	V_{DD}		2.8 / 1.8	V
Control Voltage (High)	V _{CTL(H)}		1.8	V
Control Voltage (Low)	$V_{\text{CTL}(L)}$		0	V
Supply Current1 (Active mode)	I _{DD}	V _{DD} =2.8V, V _{CTL} =1.8V	4.13	mA
Supply Current2 (Active mode)	I _{DD}	V _{DD} =1.8V, V _{CTL} =1.8V	3.43	mA
Supply Current3 (Stand-by mode)	I _{DD}	V _{DD} =2.8V, V _{CTL} =0V	0.1	μA
Supply Current4 (Stand-by mode)	I _{DD}	V _{DD} =1.8V, V _{CTL} =0V	0.0	μΑ
Control Current	I _{CTL}	V _{CTL} =1.8V	6.6	μA

■ Electrical characteristics (RF, V_{DD}=2.8V)

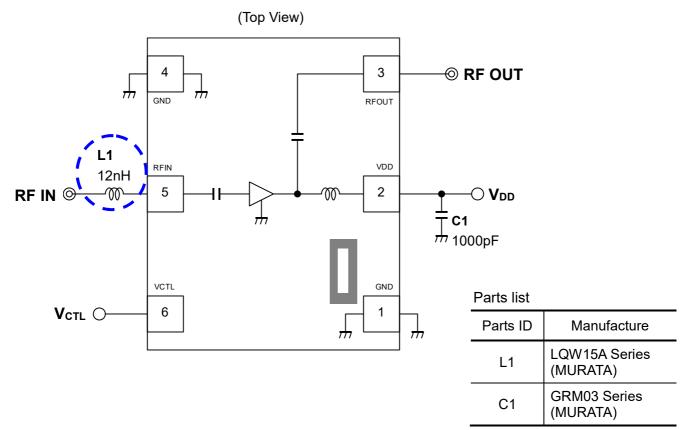
General conditions: V_{DD} =2.8V, V_{CTL} =1.8V, f_{RF} =1550 to1615MHz, T_a =+25°C, Z_s = Z_l =50 Ω , with application circuit **PARAMETER SYMBOL** CONDITIONS **MEASURED DATA** UNITS Exclude PCB and connector Small Signal Gain Gain 19.0 to 19.1 dB losses (0.18dB) Exclude PCB and connector NF Noise Figure 0.56 to 0.59 dB losses (0.08dB) Input Power at 1dB Gain P-_{1dB}(IN) -13.6 to -13.2 dBm **Compression Point** Input 3rd Order $f1=f_{RF}$, f2=f1+/-1MHz, IIP3 -2.1 dBm Intercept Point Pin=-30dBm f₁=1712.7MHz, Pin=-20dBm, Out of Band Input 3rd IIP3_OB f_2 =1850MHz, Pin=-20dBm, -0.4 dBm Order Intercept Point f_{meas} =1575.4MHz RF IN Port Return Loss RLi 8.8 to 10.3 dB RF OUT Port Return Loss RLo 11.1 to 11.8 dB

■ ELECTRICAL CHARACTERISTICS (RF, V_{DD}=1.8V)

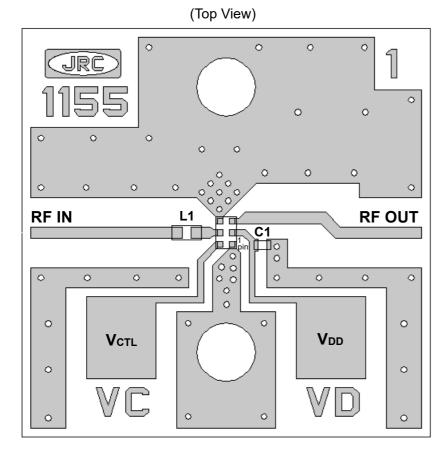
General conditions: V_{DD} =1.8V, V_{CTL} =1.8V, f_{RF} =1550 to1615MHz, T_a =+25°C, Z_s = Z_l =50 Ω , with application circuit

PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Small Signal Gain	Gain	Exclude PCB and connector losses (0.18dB)	18.3 to 18.5	dB
Noise Figure	NF	Exclude PCB and connector losses (0.08dB)	0.59 to 0.62	dB
Input Power at 1dB Gain Compression Point	P- _{1dB} (IN)		-16.5 to -16.1	dBm
Input 3rd Order Intercept Point	IIP3	f1=f _{RF} , f2=f1+/-1MHz, Pin=-30dBm	-5.3	dBm
Out of Band Input 3rd Order Intercept Point	IIP3_OB	f_1 =1712.7MHz, Pin=-20dBm, f_2 =1850MHz, Pin=-20dBm, f_{meas} =1575.4MHz	-3.6	dBm
RF IN Port Return Loss	RLi		8.4 to 9.8	dB
RF OUT Port Return Loss	RLo		10.3 to 11.5	dB

■ APPLICATION CIRCUIT (Using LQW15A Series high-Q inductor)



■ EVALUATION BOARD (Using LQW15A Series high-Q inductor)



PCB Information

Material: FR-4 Thickness: 0.2mm Microstrip line width:

 $\begin{array}{c} \text{0.4mm } (Z_0\text{=}50\Omega) \\ \text{Outline size:} \\ \text{14.0mm x 14.0mm} \end{array}$

■ NOISE FIGURE MEASUREMENT BLOCK DIAGRAM

Measuring instruments

NF Analyzer : Agilent N8973A Noise Source : Agilent 346A

Setting the NF analyzer

Measurement mode form

Device under test : Amplifier

System downconverter : off

Mode setup form

Sideband : LSB

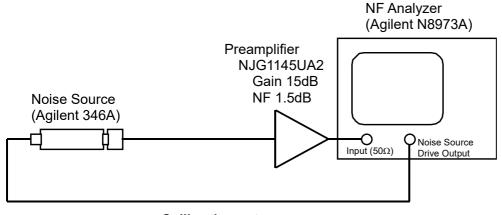
Averages : 16

Average mode : Point

Bandwidth : 4MHz

Loss comp : off

Tcold : setting the temperature of noise source (303.15K)

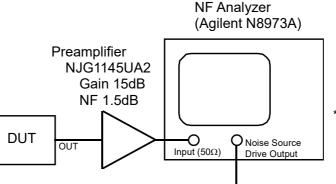


- * Preamplifier is used to improve NF measurement accuracy.
- * Noise source, preamplifier and NF analyzer are connected directly.

Calibration setup

Noise Source

(Agilent 346A)

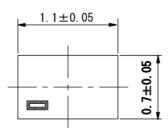


Measurement Setup

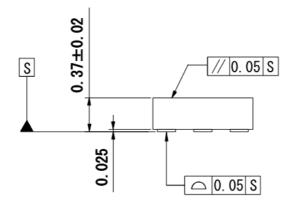
* Noise source, DUT, preamplifier and NF analyzer are connected directly.

■ PACKAGE OUTLINE (EPFFP6-X2)

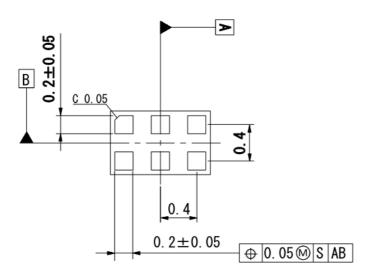




SIDE VIEW



BOTTOM VIEW



Unit : mm Substrate : FR4 Terminal treat : Au

Molding material : Epoxy resin Weight (typ.) : 0.7mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions.

The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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 - Aerospace Equipment
 - Equipment Used in the Deep Sea
 - · Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
 - · Life Maintenance Medical Equipment
 - · Fire Alarms / Intruder Detectors
 - Vehicle Control Equipment (automotive, airplane, railroad, ship, etc.)
 - Various Safety Devices
 - · Traffic control system
 - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
 - 8-1. Quality Warranty Period
 - In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
 - 8-2. Quality Warranty Remedies
 - When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.
 - Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
 - 8-3. Remedies after Quality Warranty Period
 - With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



Official website

https://www.nisshinbo-microdevices.co.jp/en/

Purchase information

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